

TC74VHC86F, TC74VHC86FN, TC74VHC86FT

Quad Exclusive OR Gate

The TC74VHC86 is an advanced high speed CMOS QUAD EXCLUSIVE OR GATE fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit includes an output buffer, which provides high noise immunity and stable output.

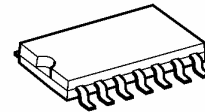
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

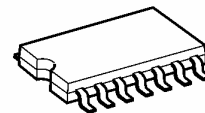
- High speed: $t_{pd} = 4.8 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC}(\text{opr}) = 2 \text{ V}$ to 5.5 V
- Low noise: $V_{OLP} = 0.8 \text{ V}$ (max)
- Pin and function compatible with 74ALS86

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74VHC86F

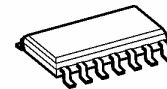


SOP14-P-300-1.27A



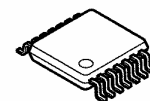
SOP14-P-300-1.27

TC74VHC86FN



SOL14-P-150-1.27

TC74VHC86FT

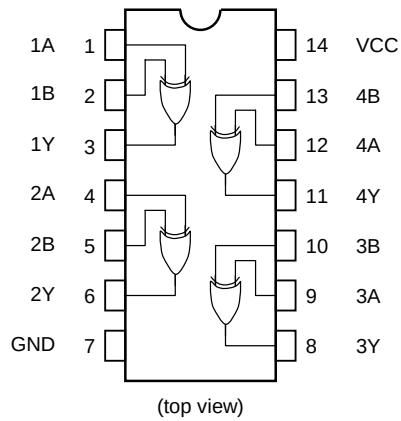


TSSOP14-P-0044-0.65A

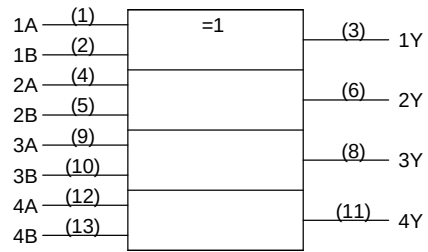
Weight

SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol



Truth Table

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC VCC/ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		V _{CC} (V)	Ta = 25°C			Ta = −40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V _{IH}	—		2.0 3.0 to 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	— —	V
Low-level input voltage	V _{IL}	—		2.0 3.0 to 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
I _{OH} = −8 mA	4.5	3.94		—	—	3.80	—			
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
I _{OL} = 8 mA	4.5	—		—	0.36	—	0.44			
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	2.0	—	20.0	μA

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
		V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH} t_{pHL}	3.3 ± 0.3	15	—	7.0	11.0	1.0	13.0	ns
			50	—	9.5	14.5	1.0	16.5	
		5.0 ± 0.5	15	—	4.8	6.8	1.0	8.0	
			50	—	6.3	8.8	1.0	10.0	
Input capacitance	C _{IN}	—		—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note)		—	18	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

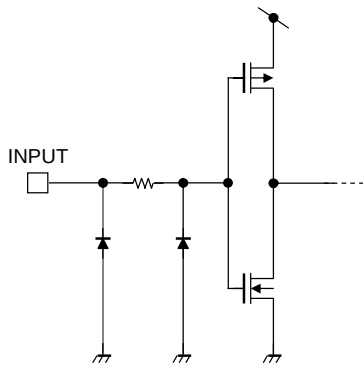
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Unit
			V _{CC} (V)	Typ. Limit	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.3 0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.3 -0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	— 3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	— 1.5	V

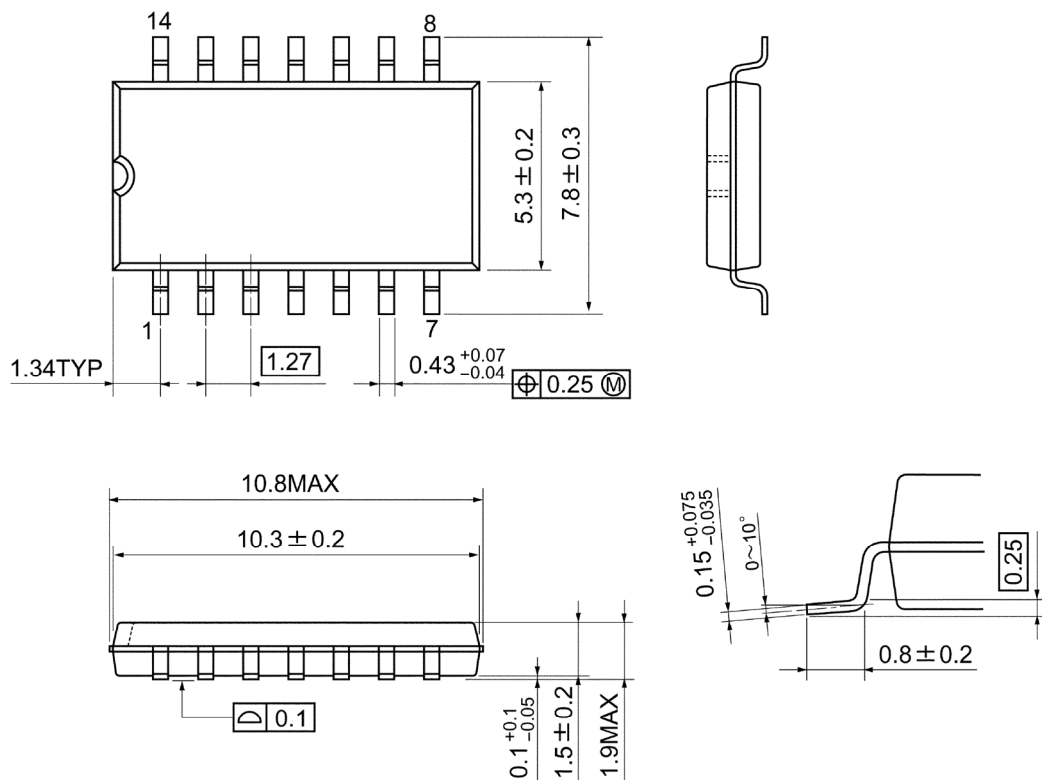
Input Equivalent Circuit



Package Dimensions

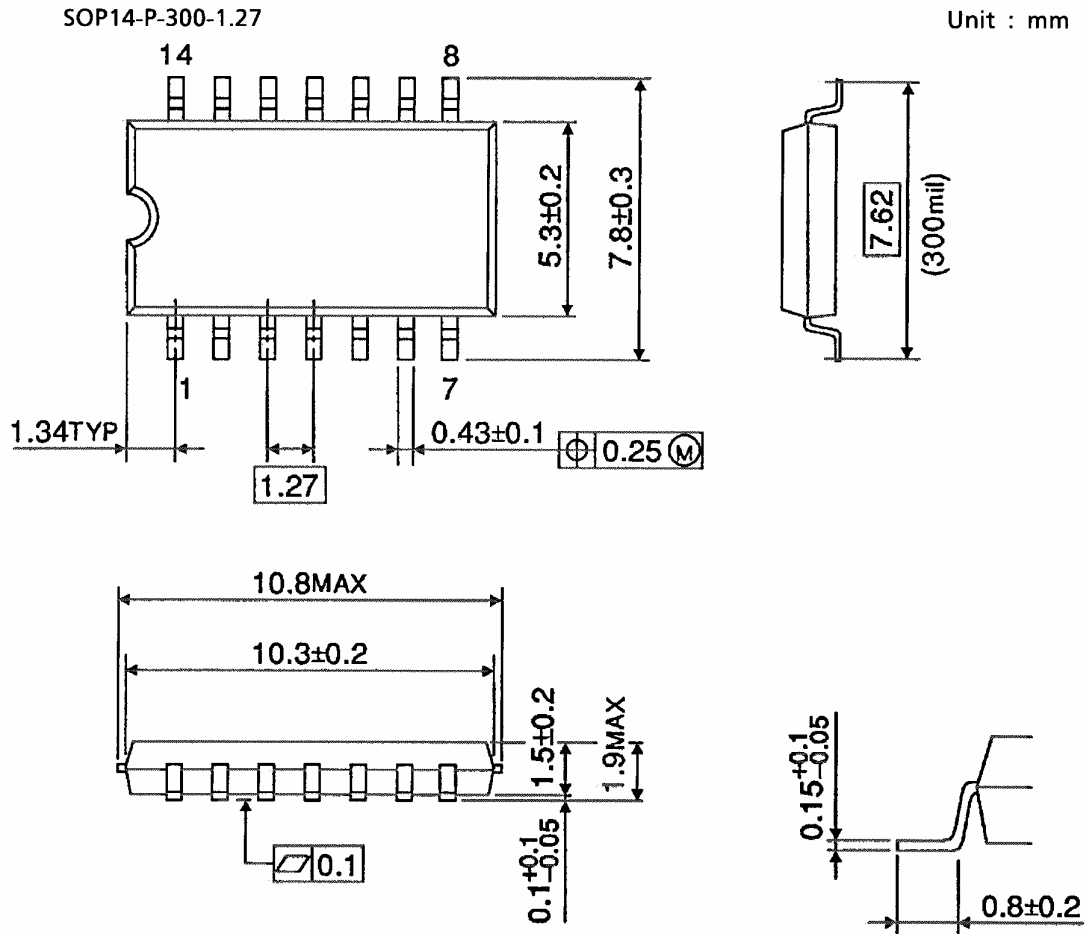
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

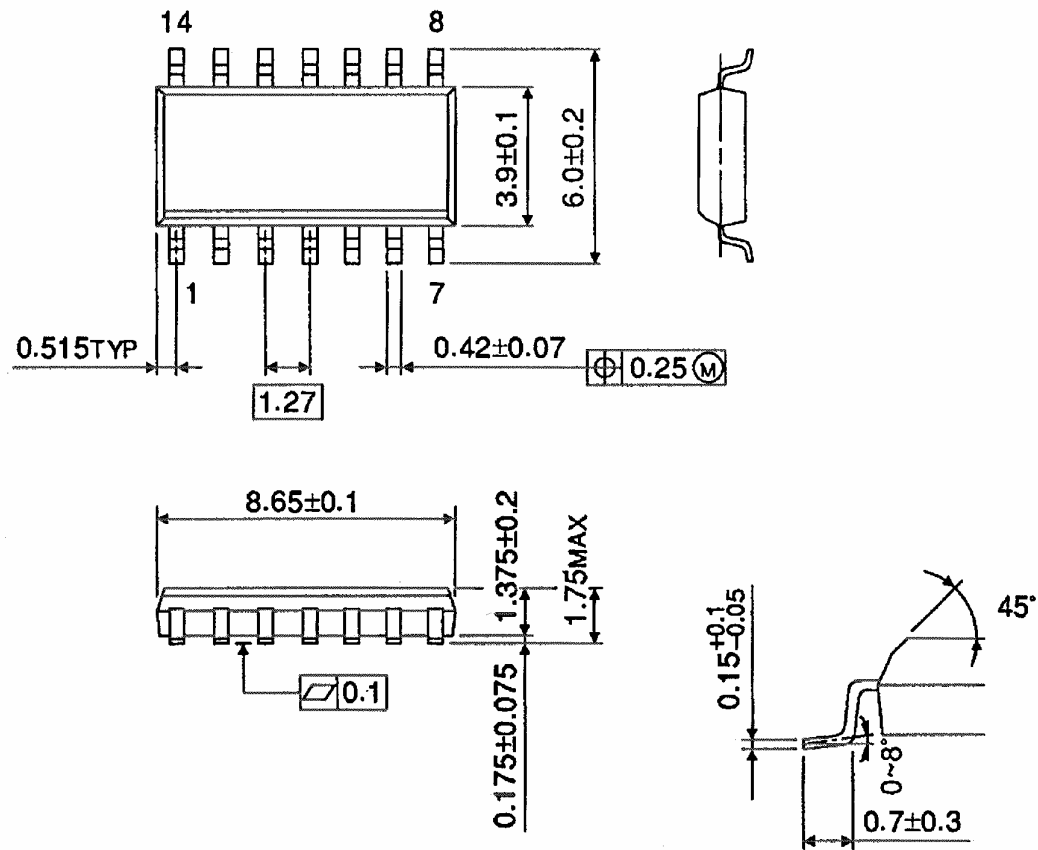


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



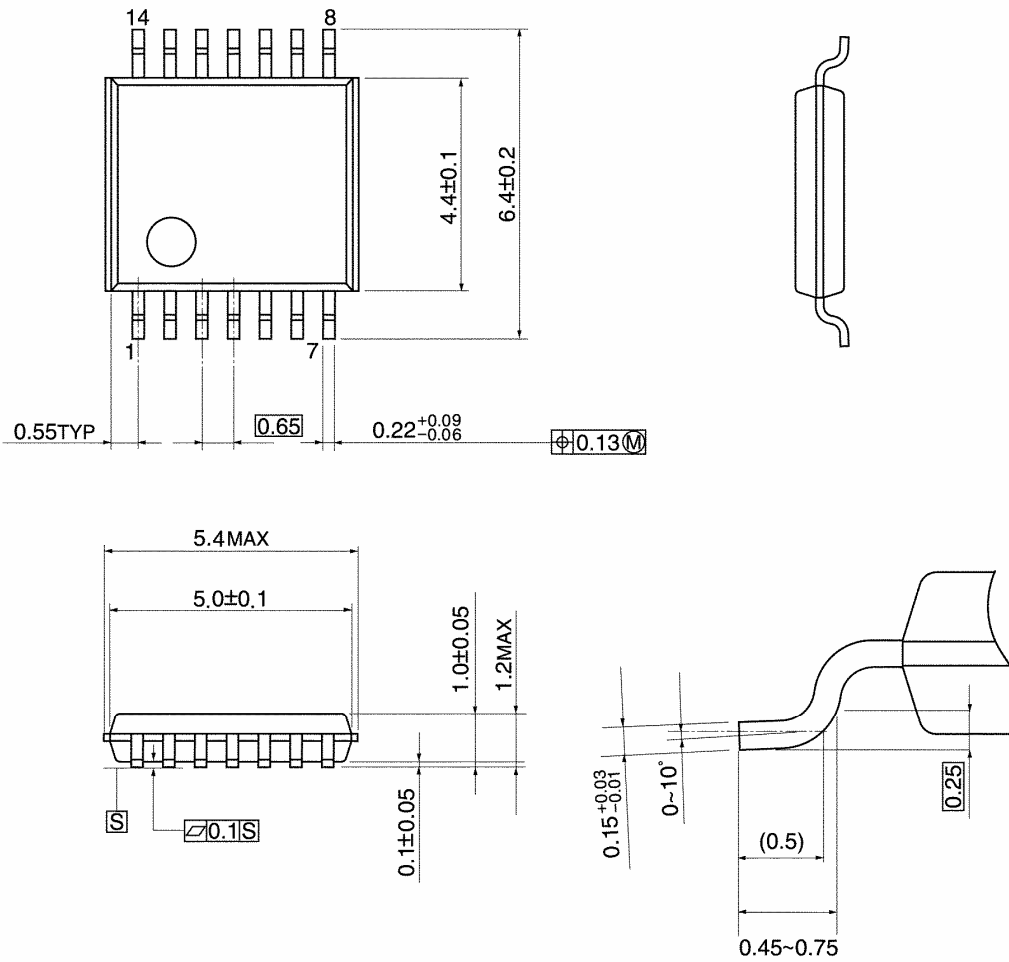
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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